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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Serial No.: 10/647,714

Conf. No.: 2476

Filing Date: 08/25/2003

Art Unit: 2818

Applicant: Khan et al.

Examiner: Le, Thao P.

Title: METAL OXIDE SEMICONDUCTOR
HETEROSTRUCTURE FIELD EFFECT
TRANSISTOR

Docket No.: SETI-0002DIV

COMMISSIONER FOR PATENTS

DESTINATION PHONE NUMBER: 703-872-9306

Transmitted herewith is: Amendment in 11 pages

in the above identified application.

- ☒ No additional fee is required.
- ☒ The Commissioner is hereby authorized to charge and credit Deposit Account No. 500999 as described below.
- ☒ Credit any overpayment.
- ☒ Charge any additional fee required.

John W. LaBatt

John W. LaBatt, Reg. No. 48,301

DATE: May 25, 2004

CERTIFICATION OF FACSIMILE TRANSMISSION

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